

Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * 150°C Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory

Mechanical Data

- * Case :JEDEC ITO-220AB molded plastic body
- * Terminals:Plated lead,solderable per MIL-STD-750, Method 2026
- * Polarity:As marked
- * Mounting Torque: 4-6kg.cm
- * Weight:1.7 g approx.

Plating pb free

MAXIMUM RATINGS

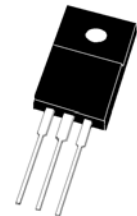
Characteristic	Symbol	MBRF2060C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	60	V
RMS Reverse Voltage	$V_{R(RMS)}$	42	V
Average Rectifier Forward Current Total Device (Rated V_R), $T_C=100^\circ\text{C}$	$I_{F(AV)}$	10 20	A
Peak Repetitive Forward Current (Rate V_R , Square Wave, 20kHz)	I_{FM}	20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	200	A
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-65 to +150	°C

ELECTRICAL CHARACTERISTICS

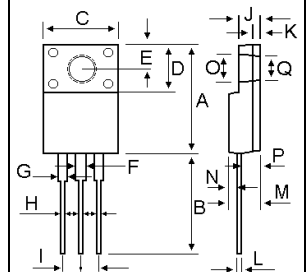
Characteristic	Symbol	MBRF2060C	Unit
Maximum Instantaneous Forward Voltage ($I_F = 10$ Amp $T_C = 25^\circ\text{C}$)	V_F	0.7	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^\circ\text{C}$) (Rated DC Voltage, $T_C = 125^\circ\text{C}$)	I_R	0.1 20	mA

SCHOTTKY BARRIER RECTIFIERS

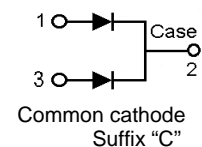
**20 AMPERES
60 VOLTS**



ITO-220AB



DIM	MILLIMETERS	
	MIN	MAX
A	15.05	15.15
B	13.35	13.45
C	10.00	10.10
D	6.55	6.65
E	2.65	2.75
F	1.55	1.65
G	1.20	1.47
H	0.55	0.65
I	2.50	2.60
J	3.00	3.20
K	1.10	1.20
L	0.55	0.65
M	4.40	4.60
N	1.15	1.25
P	2.65	2.75
O	3.35	3.45
Q	3.15	3.25



MBRF2060C

FIG-1 FORWARD CURRENT DERATING CURVE

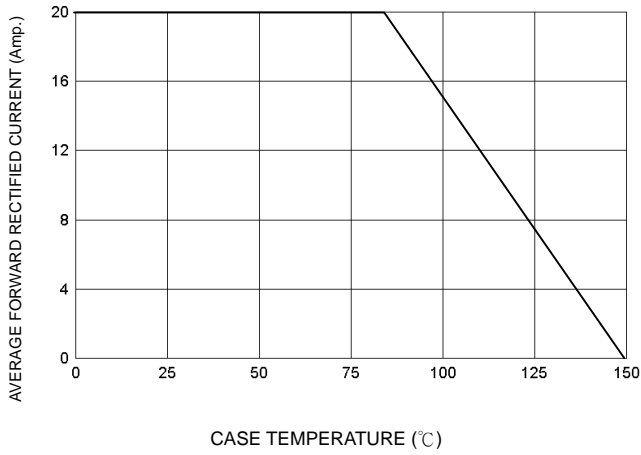


FIG-2 TYPICAL FORWARD CHARACTERISTICS

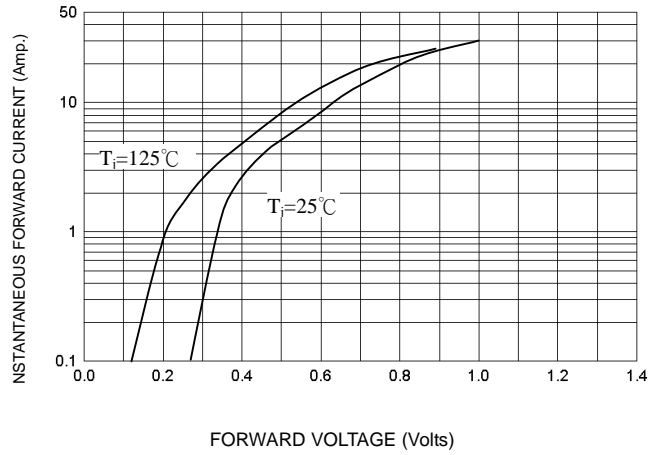


FIG-3 TYPICAL REVERSE CHARACTERISTICS

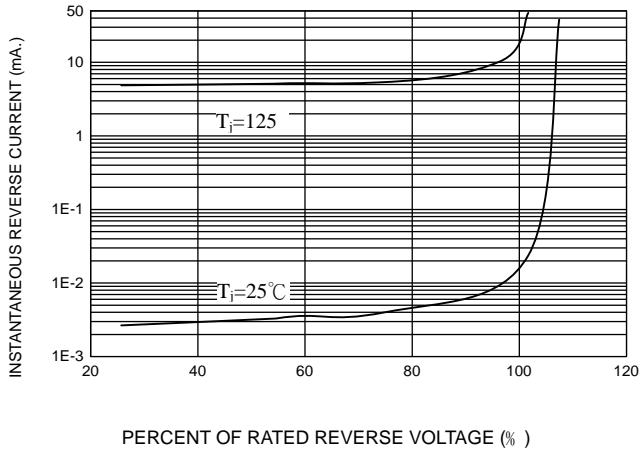


FIG-4 TYPICAL JUNCTION CAPACITANCE

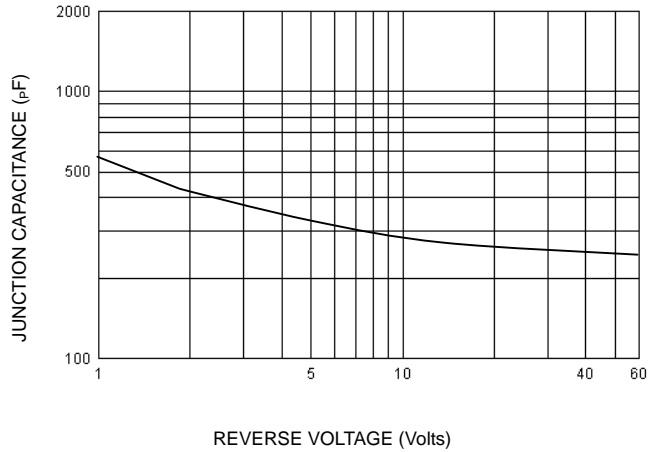
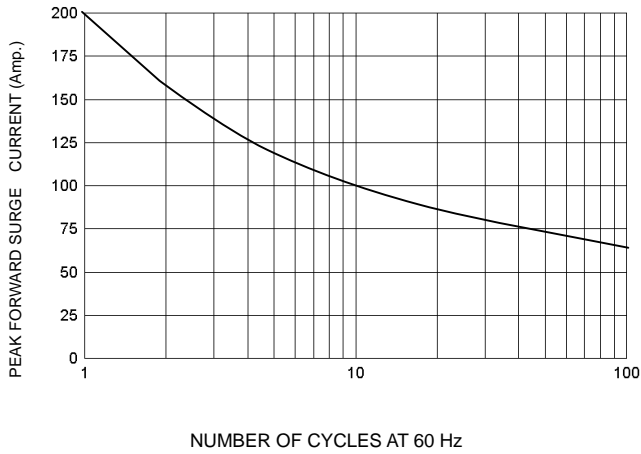


FIG-5 PEAK FORWARD SURGE CURRENT



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